## NSN 5961-01-551-1150

Diode Semiconductor Device - Page 1 of 1



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Between 2.8 millimeters and 3.0 millimeters

**Overall Height:** 

Between 0.9 millimeters and 1.1 millimeters

**Overall Width:** 

Between 2.2 millimeters and 2.5 millimeters

**End Application:** 

Control prog locig 1-03715/-1/-2/-3; plc eng rm no. 1/no. 2 10-3715-5/-6; plc aux mech nol. 1 10-3715-7; plc ac & mach/pump rm 203715-8

**Overall Width Across Flats:** 

Between 1.2 millimeters and 1.4 millimeters

Voltage Rating In Volts Per Characteristic:

30.0 reverse voltage, peak

**Current Rating Per Characteristic:** 

200.00 milliamperes source cutoff current absolute

**Maximum Operating Tempurature Per Measurement Point:** 

150.0 degrees celsius junction

**Product Name:** 

(inavy)diode bat54a

**Special Features:** 

Operating temperature: -55 to 150 degrees celsius

**Terminal Type And Quantity:** 

3 tab, solder lug

o tab, colaci la

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0